

MJD31CT4

Low voltage NPN power transistor

General features

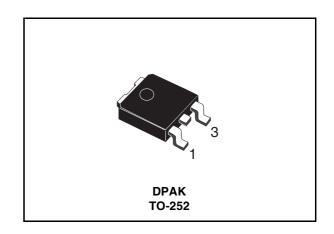
- Surface-mounting TO-252 power package in tape & reel
- In compliance with the 2002/93/EC European Directive

Applications

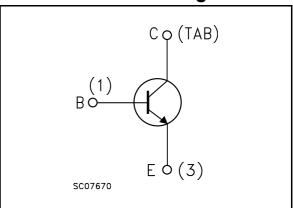
General purpose switching and amplifier transistor

Description

The device is manufactured in Planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.



Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing
MJD31CT4	MJD31C	DPAK	Tape & reel

Electrical ratings MJD31CT4

1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage (I _E = 0)	100	V
V _{CEO}	Collector-base voltage (I _B = 0)	100	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	5	V
I _C	Collector current	3	Α
I _{CM}	Collector peak current	5	Α
Ι _Β	Base current	1	Α
P _{TOT}	Total dissipation at T _c = 25°C	15	W
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

2 Electrical characteristics

(T_{case} = 25°C unless otherwise specified)

Table 2. Electrical characteristics

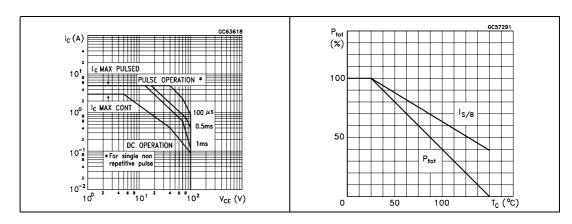
Symbol	Parameter	Test Co	onditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} =100V				20	μА
I _{CEO}	Collector cut-off current (I _B = 0)	V _{CB} =60V				50	μА
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} =5V				0.1	mA
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _B = 0)	I _C =30mA		100			٧
V _{CE(sat)} (1)	Collector-emitter saturation voltage	I _C =3A	I _B =375mA			1.2	٧
V _{BE(on)} (1)	Base-emitter on voltage	I _C =3A	V _{CE} =4V			1.8	٧
h _{FE}	DC current gain	I _C =1A I _C = 3A	V _{CE} =4V V _{CE} =4V	25 10		50	

Note (1) Pulsed duration = 300 μ s, duty cycle \leq 1.5%

2.1 Electrical characteristic (curves)

Figure 1. Safe operating area

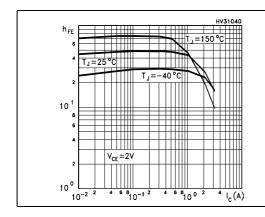
Figure 2. Derating curve



Electrical characteristics MJD31CT4

Figure 3. DC current gain

Figure 4. DC current gain



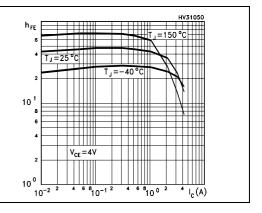
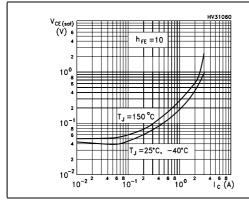


Figure 5. Collector-emitter saturation voltage

Figure 6. Base-emitter saturation voltage



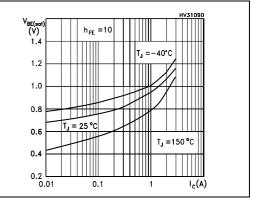
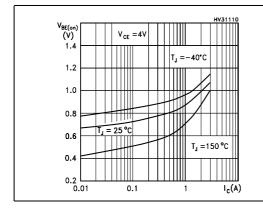
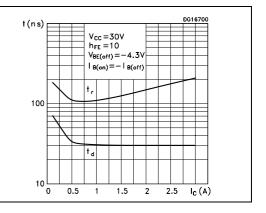


Figure 7. Collector-emitter on voltage

Figure 8. Resistive load switching time





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Figure 9. Resistive load switching time

2.2 Test circuits

Figure 10. Resistive load switching test circuit

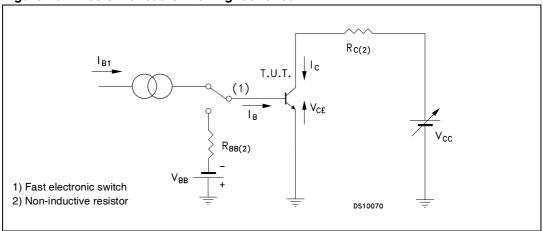
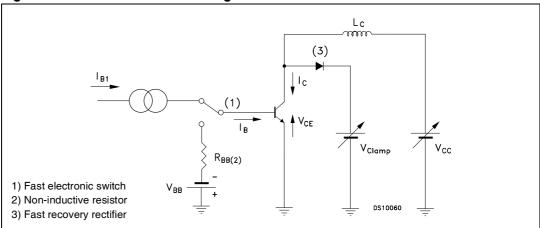


Figure 11. Inductive load switching test circuit



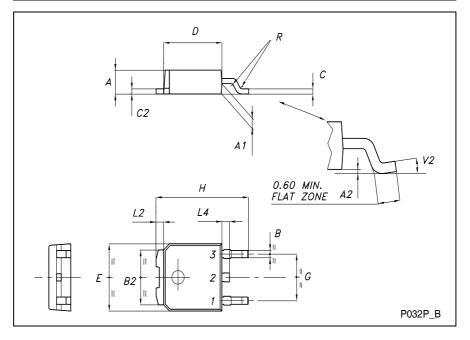
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3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-252 (DPAK) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	2.20		2.40	0.087		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
В	0.64		0.90	0.025		0.035
B2	5.20		5.40	0.204		0.213
С	0.45		0.60	0.018		0.024
C2	0.48		0.60	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.60	0.252		0.260
G	4.40		4.60	0.173		0.181
Н	9.35		10.10	0.368		0.398
L2		0.8			0.031	
L4	0.60		1.00	0.024		0.039
V2	0°		8°	0°		0°



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Revision history MJD31CT4

4 Revision history

Table 3. Revision history

Date	Revision	Changes
01-Dec-2000	1	Initial release.
20-Apr-2007	2	The document has been reformatted. New graphics have been added.

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